



TAIWAN LITON ELECTRONIC 24E D ■ 8835547 0000004 7 ■ T-41-83

General Purpose Type Photocoupler

LTK4N25/LTK4N26/LTK4N27/LTK4N28

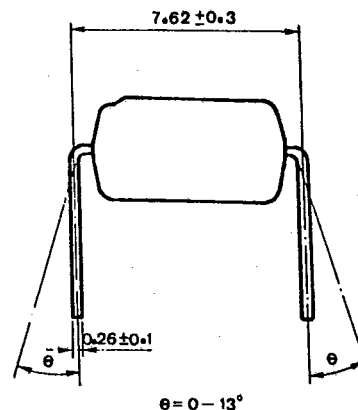
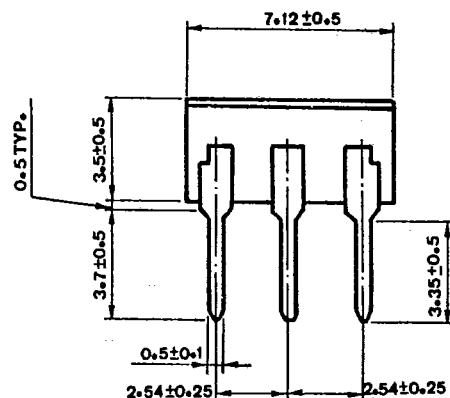
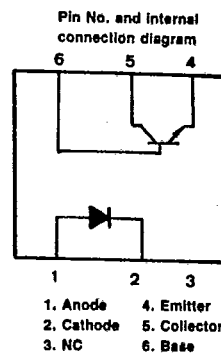
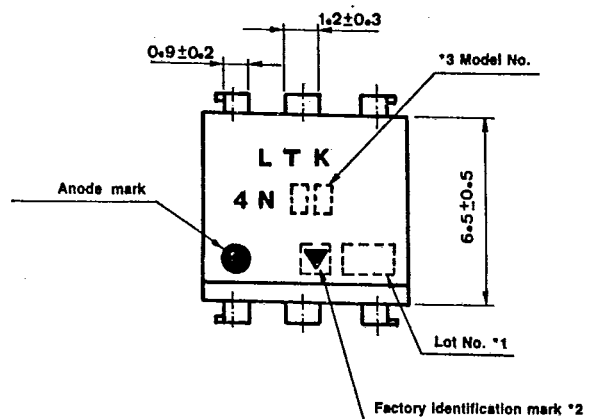
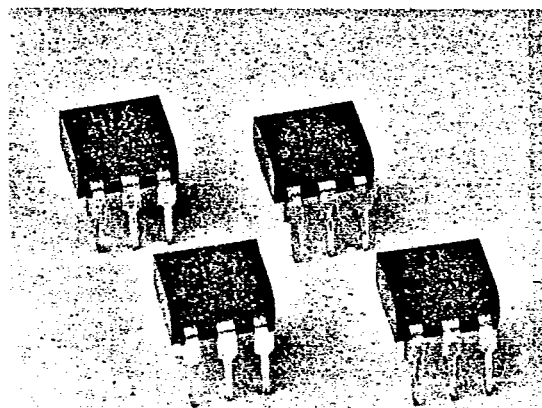
■ FEATURES

1. Response time
tr: TYP. $3\mu s$ at $V_{CE} = 10V$, $I_C = 2mA$, $R_L = 100\Omega$
2. UL approved (No. E113898(s))

■ APPLICATIONS

1. I/o interfaces for computers
2. System appliances, measuring instruments
3. Signal transmission between circuits of different potentials and impedances

■ OUTLINE DIMENSIONS (UNIT: mm)



*1 2-digit number marked according to DIN standard
*2 Factory identification mark shall be or shall not be marked.

* Model No.
LTK4N25
LTK4N26
LTK4N27
LTK4N28

■ RATINGS AND CHARACTERISTICS

• Absolute maximum ratings

(Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	80	mA
	*1 Peak forward current	I_{FM}	3	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	150	mW
Output	Collector-emitter voltage	V_{CEO}	30	V
	Collector-base voltage	V_{CBO}	70	V
	Emitter-collector voltage	V_{ECO}	7	V
	Collector current	I_C	100	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	250	mW
*2 Isolation voltage	LTK4N25	V_{iso}	2,500	V_{rms}
	LTK4N26		1,500	
	LTK4N27		1,500	
	LTK4N28		500	
Operating temperature		T_{opr}	-55 ~ +100	°C
Storage temperature		T_{stg}	-55 ~ +150	°C
*3 Soldering temperature		T_{sol}	260	°C

*1 Pulse width $\leq 1\mu s$, Duty ratio: 0.001

*2 AC for 1 minute, RH = 40 ~ 60% RH

*3 For 10 seconds

(Ta=25°C)

• Electro-optical characteristics

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward voltage	V_F	—	1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse current	I_R	—	—	10	μA	$V_R = 4\text{V}$
	Terminal capacitance	C_t	—	50	—	pF	$V = 0, F = 1\text{kHz}$
Output	Collector dark current	LTK4N25/26/27	I_{CEO}	—	—	nA	$V_{CE} = 10\text{V}$ $I_F = 0$
		LTK4N28		—	—		
	Collector-emitter breakdown voltage		BV_{CEO}	30	—	—	V $I_C = 0.1\text{mA}, I_F = 0$
	Emitter-collector breakdown voltage		BV_{ECO}	7	—	—	V $I_E = 10\mu\text{A}, I_F = 0$
	Collector-base breakdown voltage		BV_{CBO}	70	—	—	V $I_C = 0.1\text{mA}, I_F = 0$
Transfer characteristics	*1 Collector current	LTK4N25/26	I_C	2	—	mA	$I_F = 10\text{mA}$ $V_{CE} = 10\text{V}$
		LTK4N27/28		1	—		
	Collector-emitter saturation voltage		$V_{CE}(\text{sat})$	—	0.1	0.5	V $I_F = 50\text{mA}, I_C = 2\text{mA}$
	Isolation resistance		R_{ISO}	5×10^{10}	1×10^{11}	—	Ω DC500V, 40~60%RH
	Floating capacitance		C_f	—	1.0	—	pF $V = 0, f = 1\text{MHz}$
	Response time (Rise)		t_r	—	3	—	μs $V_{CE} = 10\text{V}, R_{BE} = \infty$ $R_L = 100\Omega, I_C = 2\text{mA}$
	Response time (Fall)		t_f	—	3	—	

*1 Pulse test: input pulse width = $300\mu\text{s}$, Duty ratio ≤ 0.02 , $CTR = \frac{I_C}{I_F} \times 100\%$

■ SUPPLEMENT**• Isolation voltage shall be measured in the following method.**

- (1) short between anode and cathode on the primary side and between collector, emitter and base on the secondary side.
- (2) The isolation voltage tester with a zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

• Inspection standard

Outgoing inspection standard for LITON products are shown below.

- (1) A single sampling plan, normal inspection level II based on MIL-STD-105D is applied. The AQL according to the inspection items are shown below.

Defect	Inspection Item	AQL(%)	Judgement
Major defect	• Electrical characteristics • Unreadable marking • Open, short	0.25	Depend on the specification
Minor defect	• Appearance • Dimension	0.4	

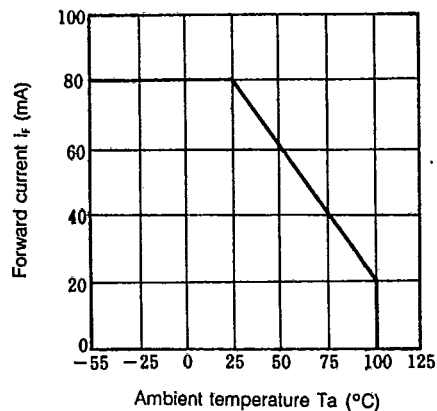
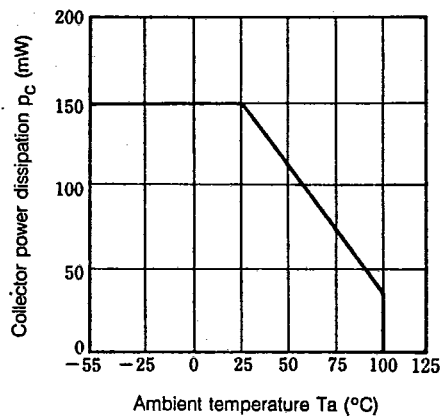
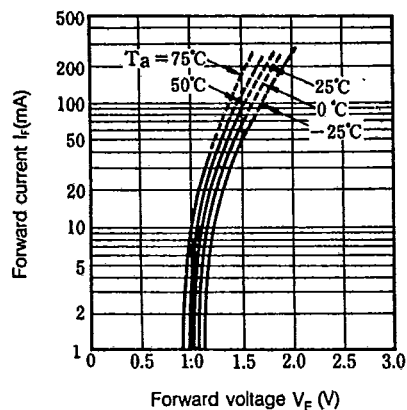
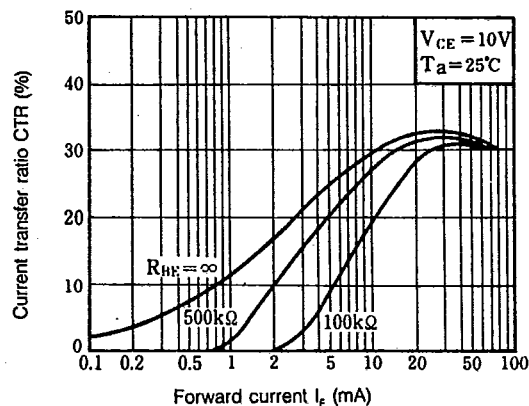
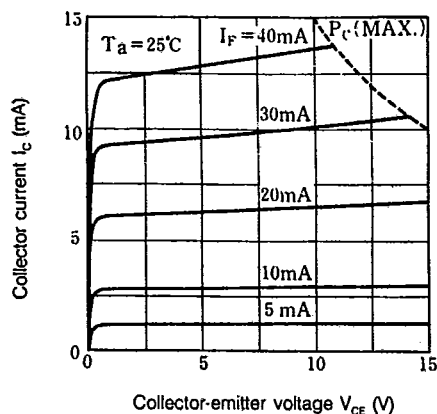
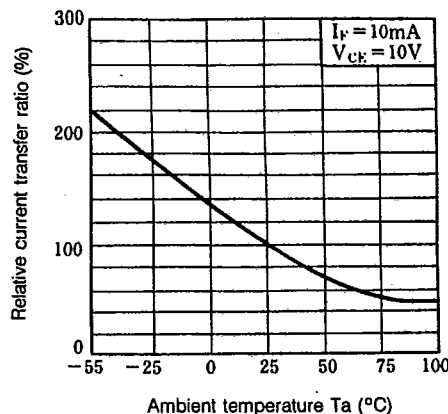
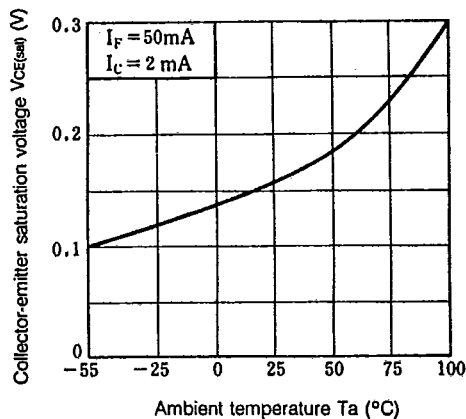
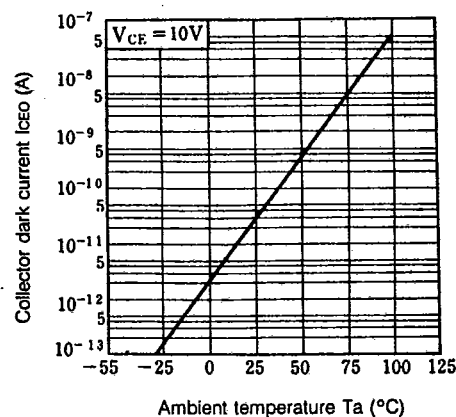
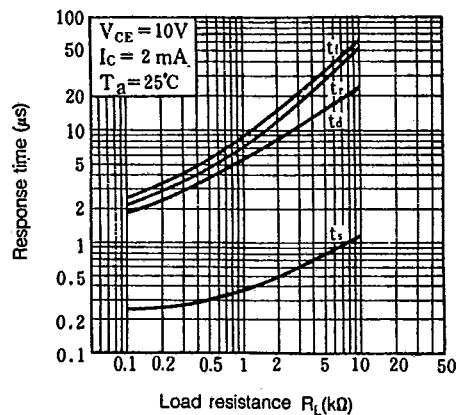
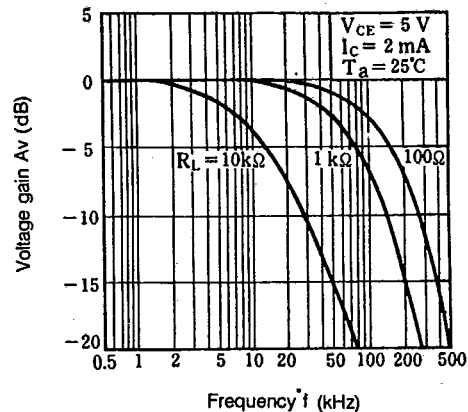
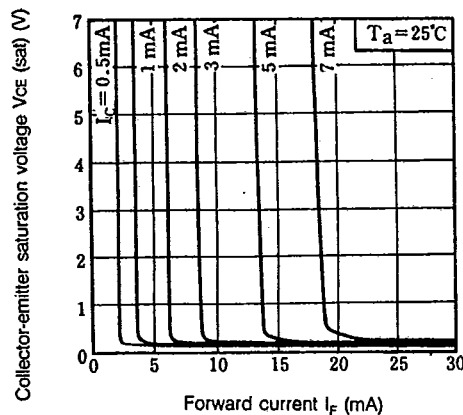
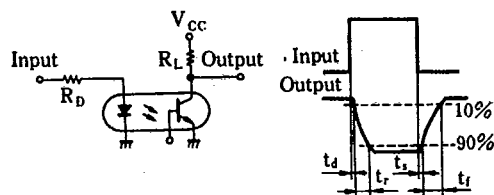
Fig. 1 Forward Current vs. Ambient Temperature**Fig. 2** Collector Power Dissipation vs. Ambient Temperature**Fig. 3** Forward Current vs. Forward Voltage**Fig. 4** Current Transfer Ratio vs. Forward Current**Fig. 5** Collector Current vs. Collector-emitter Voltage**Fig. 6** Relative Current Transfer Ratio vs. Ambient Temperature

Fig. 7 Collector-emitter Saturation Voltage vs. Ambient Temperature**Fig. 8** Collector Dark Current vs. Ambient Temperature**Fig. 9** Response Time vs. Load Resistance**Fig. 10** Frequency Response**Fig. 11** Collector-emitter Saturation Voltage vs. Forward Current

Test Circuit for Response Time



Test circuit for Frequency Response

